



# **MMST5551**

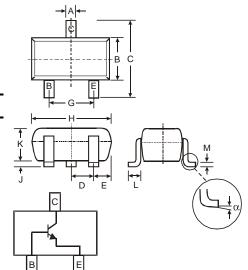
#### NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### **Features**

- **Epitaxial Planar Die Construction**
- Complementary PNP Type Available (MMST5401)
- Ideal for Low Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

## **Mechanical Data**

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: K4N, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



SOT-323										
Dim	Min	Max								
Α	0.25	0.40								
В	1.15	1.35								
С	2.00	2.20								
D	0.65 Nominal									
E	0.30	0.40								
G	1.20	1.40								
Н	1.80 2.20									
J	0.0 0.10									
K	0.90	1.00								
L	0.25	0.40								
M	0.10	0.18								
α	0°	8°								
All Din	nensions	in mm								

### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	180	V
Collector-Emitter Voltage	V <sub>CEO</sub>	160	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current - Continuous (Note 1)	I <sub>C</sub>	200	mA
Power Dissipation (Note 1)	P <sub>d</sub>	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics @TA = 25°C unless otherwise specified

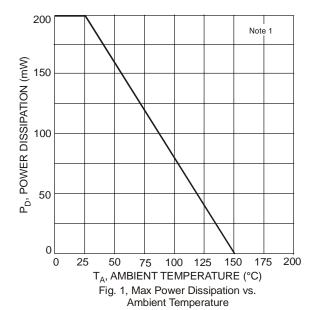
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	180	_	V	$I_C = 100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	160	_	V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6.0	_	V	$I_E = 10\mu A, I_C = 0$
Collector Cutoff Current			50	nA	V <sub>CB</sub> = 120V, I <sub>E</sub> = 0
Collector Catori Carrent	I <sub>CBO</sub>	_	30	μΑ	$V_{CB} = 120V$ , $I_E = 0$ , $T_A = 100^{\circ}C$
Emitter Cutoff Current	I <sub>EBO</sub>		50	nA	$V_{EB} = 4.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 5)					
	h <sub>FE</sub>	80	_		$I_C = 1.0 \text{mA}, V_{CE} = 5.0 \text{V}$
DC Current Gain		80 30	250	_	$I_C = 10 \text{mA}, V_{CE} = 5.0 \text{V}$
			_		$I_C = 50 \text{mA}, V_{CE} = 5.0 \text{V}$
Collector-Emitter Saturation Voltage	V		0.15	V	$I_C = 10mA$ , $I_B = 1.0mA$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		0.20	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
Raco Emittor Saturation Voltago	V		1.0	V	$I_C = 10mA$ , $I_B = 1.0mA$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	1.0	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C <sub>obo</sub>		6.0	рF	$V_{CB} = 10V, f = 1.0MHz, I_{E} = 0$
Small Signal Current Gain	h <sub>fe</sub>	50	250		$V_{CE} = 10V, I_{C} = 1.0mA, f = 1.0kHz$
Current Gain-Bandwidth Product	f <sub>T</sub>	100	300	MHz	$V_{CE} = 10V, I_{C} = 10mA, f = 100MHz$
Noise Figure	NF	_	8.0	dB	$V_{CE} = 5.0V$ , $I_C = 200\mu A$ , $R_S = 1.0k\Omega$ , $f = 1.0kHz$

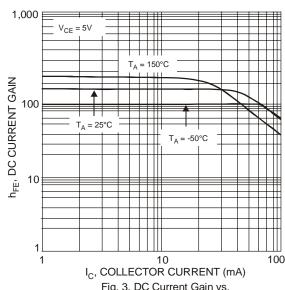
Notes:

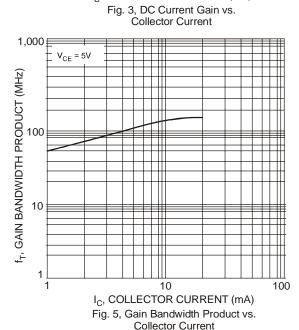
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
  Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

5. Short duration pulse test used to minimize self-heating effect.









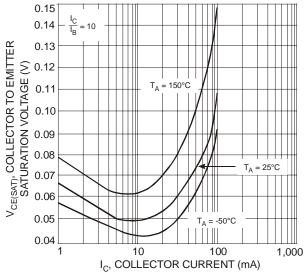
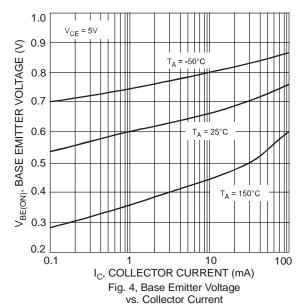


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current



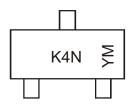


## Ordering Information (Note 4 & 6)

Device	Packaging	Shipping
MMST5551-7-F	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## Marking Information



K4N= Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Kev

-	Date Code ite															
	Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
	Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Χ	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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